

VOLTAGE RANGE: 40 - 200V

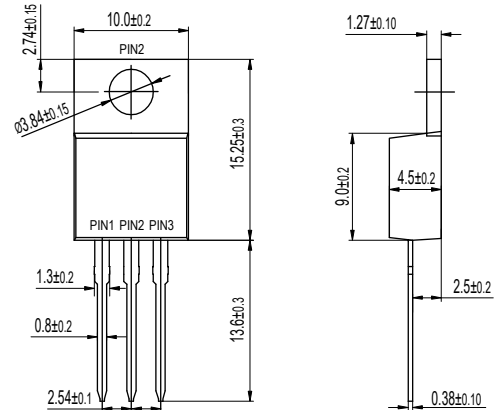
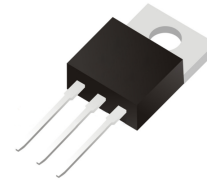
CURRENT: 30A

Features

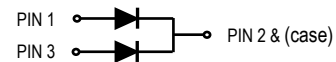
- High efficiency operation
- Low power loss
- Low stored charge majority carrier conduction
- High forward surge capability
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std (Halogen Free)

Mechanical Data

- Circuit figure: Common cathode
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: TO-220AB 1.85 grams



TO-220AB



Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

RATINGS	SYMBOL	MBR 3040CT	MBR 3045CT	MBR 3060CT	MBR 30100CT	MBR 30150CT	MBR 30200CT	UNIT
Maximum repetitive reverse voltage	VRRM	40	45	60	100	150	200	V
Maximum RMS voltage	VRMS	28	32	42	70	105	140	V
Maximum DC blocking voltage	VDC	40	45	60	100	150	200	V
Maximum average forward current per device per diode	IAV	30				15		A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	IFSM	280						A
Typical thermal resistance (Note 1)	R θ -JC	2.0						$^\circ\text{C}/\text{W}$
Operating junction temperature range	TJ	-55 to +150				-55 to +175		$^\circ\text{C}$
Storage temperature range	TSTG	-55 to +175						$^\circ\text{C}$
Maximum forward voltage per leg at IF=15A	VF	0.65	0.75	0.85	0.95		V	
Maximum average reverse current at rated DC blocking voltage $T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$	IR	0.10		0.01		8		mA
		15						

Notes: 1. Thermal resistance from junction to case.

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

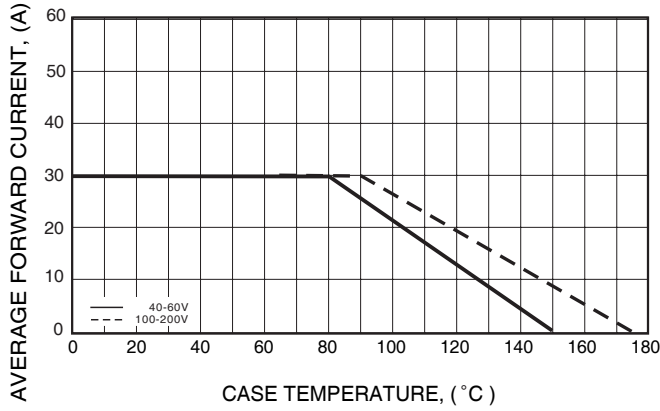


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

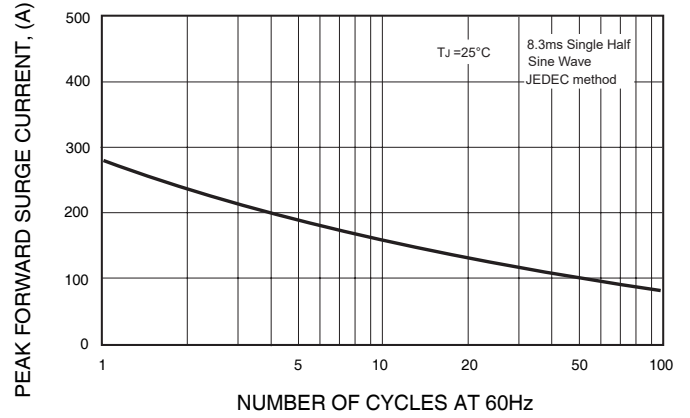


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

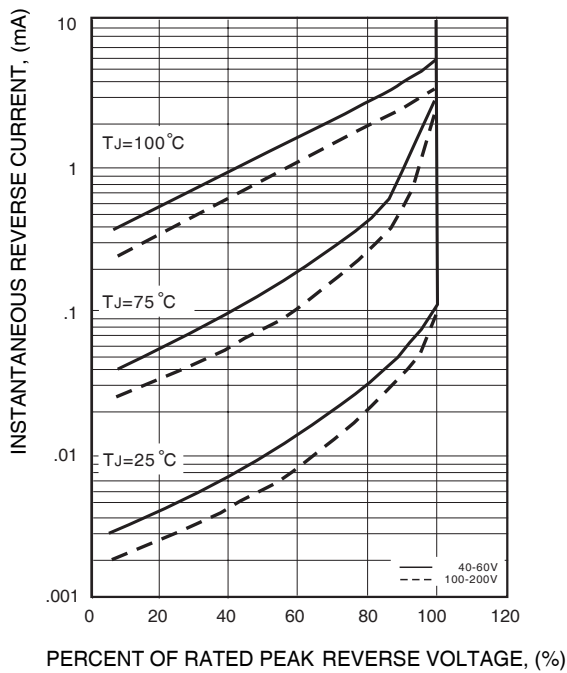


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

